

RoHS

## **Dual Common Cathode High Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
$V_{RRM}$	90 V, 100 V				
I <sub>FSM</sub>	150 A				
$V_{F}$	0.70 V				
I <sub>R</sub>	3.5 μΑ				
$T_J$ max.	175 °C				
Package	TO-220AB				
Diode variations	riations Dual common cathode				

#### **FEATURES**

Power pack



- · Lower power losses, high efficiency
- Low forward voltage drop
- · Low leakage current
- · High forward surge capability
- High frequency operation
- Solder dip 275 °C max., 10 s, per JESD 22-B106
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR20H90CTG	MBR20H100CTG	UNIT	
Maximum repetitive peak reverse voltage			90	100	V	
Working peak reverse voltage		$V_{RWM}$	90	100	V	
Maximum DC blocking voltage		$V_{DC}$	90	100	٧	
Maximum average forward rectified current T <sub>C</sub> = 150°C	total device	1	20 10		А	
	per diode	I <sub>F(AV)</sub>				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150		Α	
Peak repetitive reverse current per diode at t <sub>p</sub> = 2 μs, 1 kHz		I <sub>RRM</sub>	0.5		Α	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +175		°C	

# MBR20H90CTG, MBR20H100CTG

# Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 10 A	T <sub>J</sub> = 25 °C	0.80	0.85	V	
		I <sub>F</sub> = 10 A	T <sub>J</sub> = 125 °C	0.64	0.70		
		I <sub>F</sub> = 20 A	T <sub>J</sub> = 25 °C	0.87	0.93		
		I <sub>F</sub> = 20 A	T <sub>J</sub> = 125 °C	0.74	0.80		
Maximum reverse current per diode at working peak reverse voltage	I <sub>R</sub> <sup>(1)</sup>		T <sub>J</sub> = 25 °C	-	3.5	μΑ	
			T <sub>J</sub> = 125 °C	-	4.5	mA	

#### Note

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	UNIT		
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR20H100CTG-E3/45	1.85	45	50/tube	Tube	
TO-220AB	MBR20H100CTGHE3/45 (1)	1.85	45	50/tube	Tube	

#### Note

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

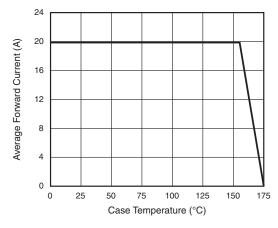


Fig. 1 - Forward Derating Curve

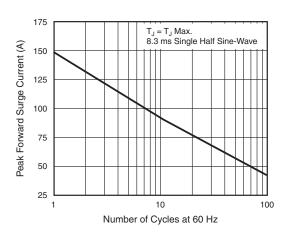


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

<sup>(1)</sup> AEC-Q101 qualified

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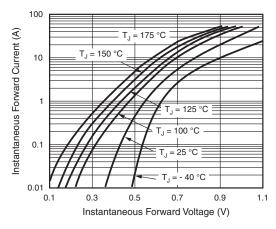


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

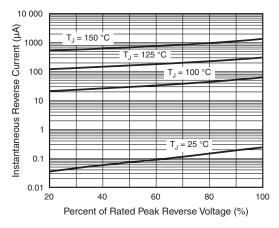


Fig. 4 - Typical Reverse Characteristics Per Diode

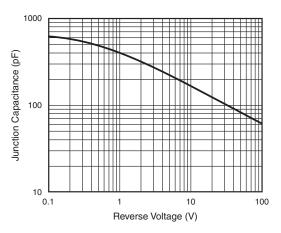


Fig. 5 - Typical Junction Capacitance Per Diode

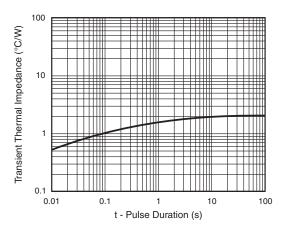
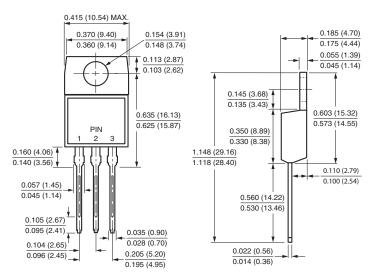


Fig. 6 - Typical Transient Thermal Impedance Per Diode

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### TO-220AB





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